



BMKE041N65BA

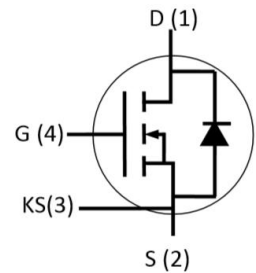
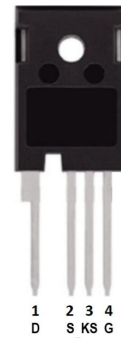
Specifically designed for Automotive applications, this SUPERFET MOSFET utilizes the latest processing techniques to achieve extremely low on-resistance per unit area.

本产品是一款专为汽车应用设计的超级结 MOSFET 产品，采用了最先进的工艺技术，产品的单位面积导通电阻低。

Features:

特性

- 650V Drain-Source Voltage
650V的漏极-源极电压
- Ultra Low Gate Charge
超低栅极电荷
- Low Effective Output Capacitance
低的有效输出电容
- 100% Avalanche Tested
100%通过雪崩测试



Applications:

应用

- EV Charger
汽车充电器
- Industrial Power Supplies
工业电源
- Solar
太阳能

Type 型号	V _{DS} [V] 漏极-源极电压	R _{DS(on)} [mΩ] 导通电阻	T _{Jmax} [°C] 最高结温	Marking 标记	Package 封装
BMKE041N65BA	650	41	150	041N65BA	TO247-4L

**BMKE041N65BA****Maximum Rated Values****最大额定参数**

Parameter 参数	Symbol 符号	Value 值	Unit 单位
Drain to Source Voltage, $T_j \geq 25^\circ\text{C}$ 漏极-源极电压, $T_j \geq 25^\circ\text{C}$	V_{DSS}	650	V
Gate to Source Voltage, (static) 栅极-源级极电压, 静态	V_{GSS}	± 30	V
Gate to Source Voltage, (AC, $f > 1\text{Hz}$) 栅极-源级极电压, (AC, $f > 1\text{Hz}$)		± 30	
Drain Current, $T_c = 25^\circ\text{C}$ 漏电极电流, $T_c = 25^\circ\text{C}$	I_{D}	80	A
Drain Current, $T_c = 100^\circ\text{C}$ 漏电极电流, $T_c = 100^\circ\text{C}$		50	
Pulsed Drain Current, t_p limited by $T_{j\text{max}}$ 漏电极脉冲电流, 脉宽时间受 $T_{j\text{max}}$ 限制	$I_{\text{D,pulse}}$	255	
Single Pulsed Avalanche Energy, $T_c = 25^\circ\text{C}$ 单脉冲雪崩能量, $T_c = 25^\circ\text{C}$	E_{AS}	2066	mJ
Single Pulsed Avalanche Current, $T_c = 25^\circ\text{C}$ 单脉冲雪崩电流, $T_c = 25^\circ\text{C}$	I_{AS}	12	A
MOSFET dv/dt ruggedness	dv/dt	26	V/ns
Power Dissipation, $T_c = 25^\circ\text{C}$ 常温耗散功率, $T_c = 25^\circ\text{C}$	P_{D}	455	W
Maximum Junction Temperature 最高结温	$T_{j\text{max}}$	150	$^\circ\text{C}$
Operating Junction Temperature 工作结温	T_j	$-55 \dots +150$	
Storage Temperature 储存温度	T_{STG}	$-55 \dots +150$	

Thermal Resistance**热阻**

Parameter 参数	Symbol 符号	Value 值	Unit 单位
Thermal Resistance, Junction to Case, Max. 结-管壳热阻	$R_{\theta\text{JC}}$	0.205	$^\circ\text{C/W}$
Thermal Resistance, Junction to Ambient, Max. 结-环境热阻	$R_{\theta\text{JA}}$	62	$^\circ\text{C/W}$

**BMKE041N65BA****Electrical Characteristic at Tj = 25°C (unless otherwise specified)****Tj=25°C时电学特性（除非特别声明）**

Parameter 参数	Symbol 符号	Conditions 条件	Value 值			Unit 单位
			Min. 最小值	Typ. 典型值	Max. 最大值	
Static Characteristic 静态特性						
Drain to Source Breakdown Voltage 漏极-源极电压击穿电压	BV _{DSS}	V _{GS} =0V, I _D =1mA	650	-	-	V
Zero Gate Voltage Drain Current 栅源短路的漏极电流	I _{DSS}	V _{DS} =650V, V _{GS} =0V	-	-	10	uA
Gate to Body Leakage Current 栅-源漏泄电流	I _{GSS}	V _{GS} =±30V, V _{DS} =0V	-	-	100	nA
Static Drain-source On Resistance 漏-源通态电阻	R _{DS(on)}	V _{GS} =10V, I _D =32.5A	-	35	41	mΩ
Gate Threshold Voltage 栅-源阈值电压	V _{GS(th)}	V _{DS} =V _{GS} , I _D =6.5mA	3.0	-	5.0	V
Gate Resistance 栅极电阻	R _g	f=1MHz, open drain	-	1.9	-	Ω
Dynamic Characteristic 动态特性						
Input capacitance 输入电容	C _{iss}	V _{GS} =0V, V _{DS} =400V, f=200KHz	-	7372	-	pF
Output capacitance 输出电容	C _{oss}		-	167	-	
Reverse transfer capacitance 反向传输电容	C _{rss}		-	12	-	
Total Gate Charge 栅极总电荷	Q _{g(tot)}	V _{DD} =400V, I _D =24A, V _{GS} =10V	-	141.8	-	nC
Gate to Source Gate Charge 栅极-源极电荷	Q _{gs}		-	38.6	-	
Gate to Drain Charge 栅极-漏极电荷	Q _{gd}		-	72.7	-	



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Switching Characteristic at $T_j=25^{\circ}\text{C}$ (Inductive Load)

$T_j=25^{\circ}\text{C}$ 时开关特性（电感负载）

Parameter 参数	Symbol 符号	Conditions 条件	Value 值			Unit 单位
			Min. 最小值	Typ. 典型值	Max. 最大值	
MOSFET Characteristic MOSFET 特性						
Turn-on delay time 开通延迟时间	t _{d(on)}	V _{DD} =400V, V _{GS} =12V, I _D =32.5A, R _G =2Ω	-	25.5	-	ns
Rise time 上升时间	t _r		-	36.9	-	
Turn-off delay time 关断延迟时间	t _{d(off)}		-	81.8	-	
Fall time 下降时间	t _f		-	7.0	-	

SOURCE-DRAIN DIODE CHARACTERISTICS

源极-漏极二极管特性

Reverse recovery time 反向恢复时间	t_{rr}	$I_F=32.5\text{A},$ $di_F/dt=697\text{A}/\mu\text{s}$	-	141.9	-	ns
Recovered charge 恢复电荷	Q_{rr}		-	2.7	-	μC
Peak reverse recovery current 反向峰值电流	I_{rrm}		-	34.4	-	A
Source to Drain Diode Forward Voltage 源极-漏极正向电压	V_{SD}	$V_{GS}=0\text{V},$ $I_D=32.5\text{A}$	-	0.9	1.3	V



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ELECTRICAL CHARACTERISTICS

特性曲线

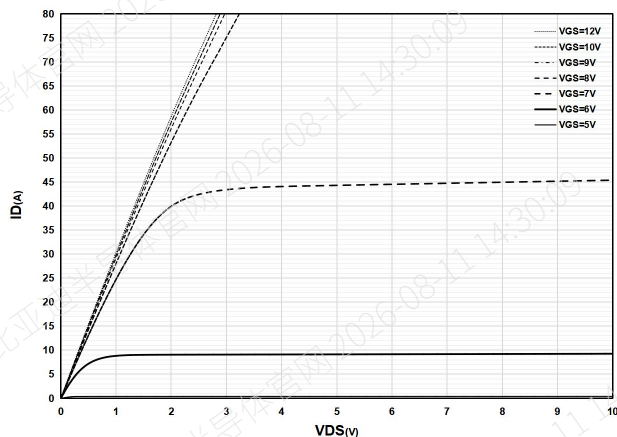


Figure 1. Typical output characteristics($T_j=25^\circ\text{C}$)

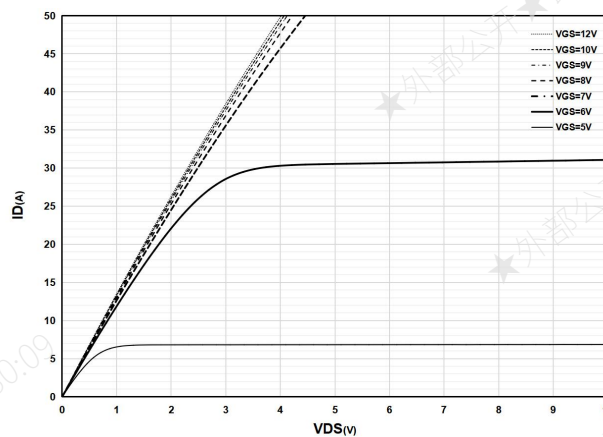


Figure 2. Typical output characteristics($T_j=150^\circ\text{C}$)

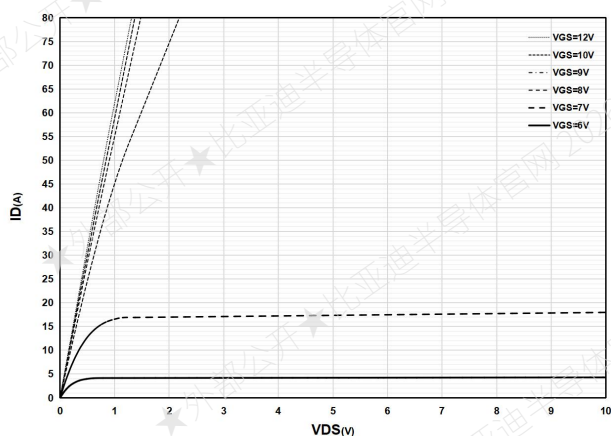


Figure 3. Typical output characteristics($T_j=-55^\circ\text{C}$)

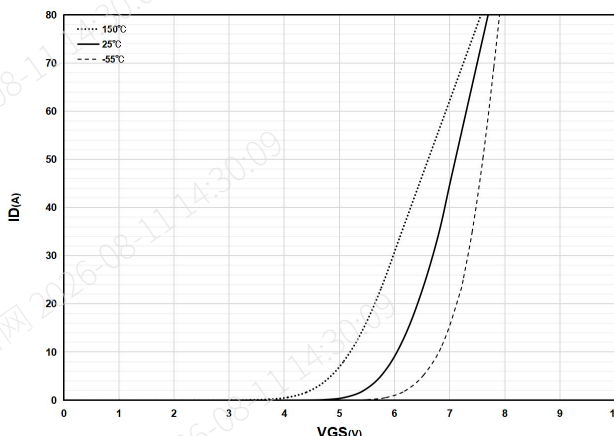


Figure 4. Typical transfer characteristics($V_{DS}=10\text{V}$)

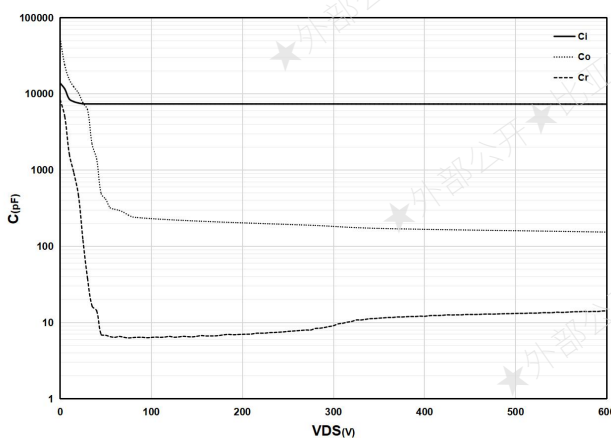


Figure 5. Typical capacitance as a function of drain-source voltage($f=200\text{KHz}$, $V_{GS}=0\text{V}$)



Figure 6. Typical drain-source on-state resistance as a function of gate-source voltage($I_D=32.5\text{A}$)

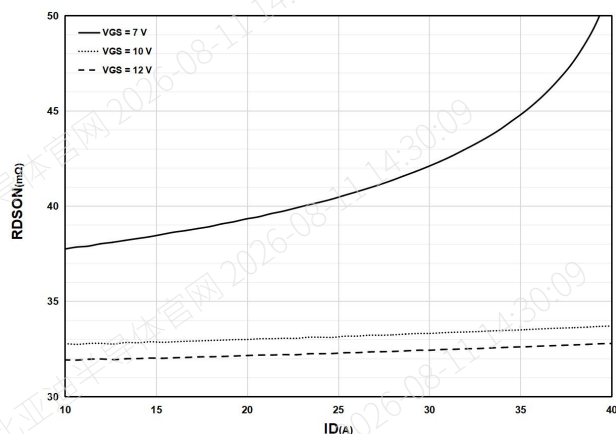
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Figure 7. Typical drain-source on-state resistance as a function of drain current

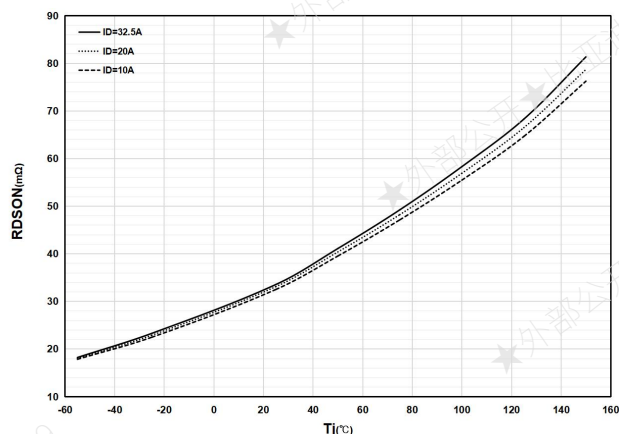


Figure 8. Typical drain-source on-state resistance as a function of junction temperature ($V_{GS}=10V$)

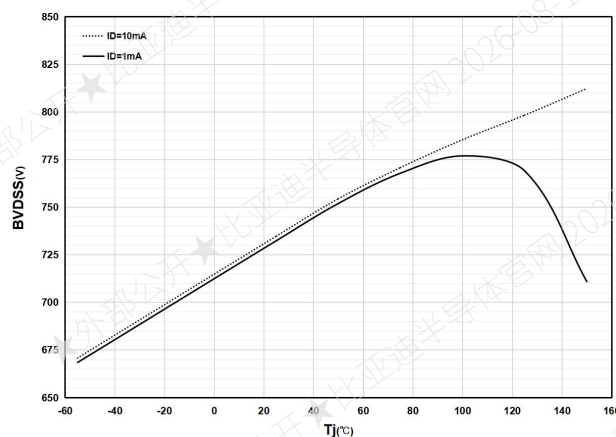


Figure 9. Typical drain-source breakdown voltage as a function of junction temperature

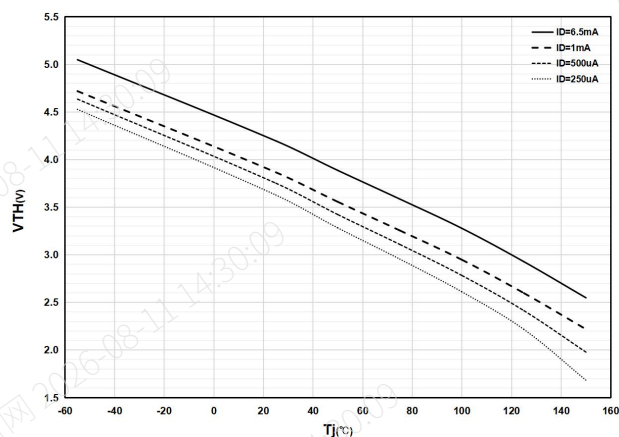


Figure 10. Typical gate threshold voltage as a function of junction temperature

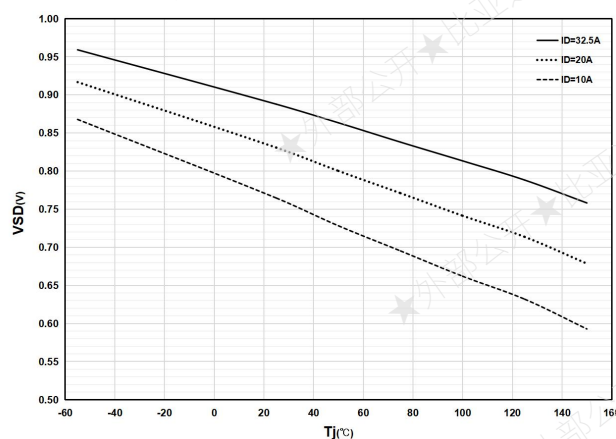


Figure 11. Typical source-drain diode forward voltage as a function of junction temperature

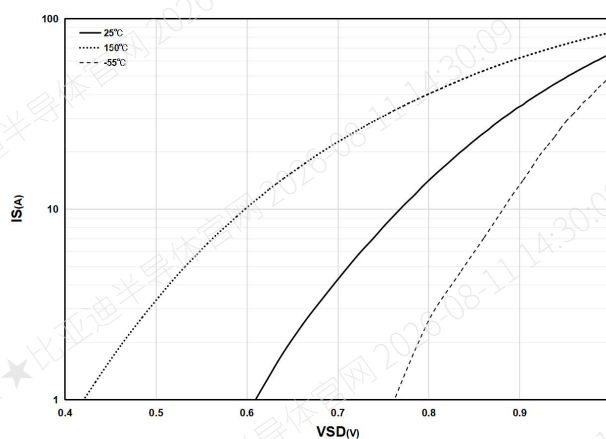


Figure 12. Typical forward characteristics of reverse diode



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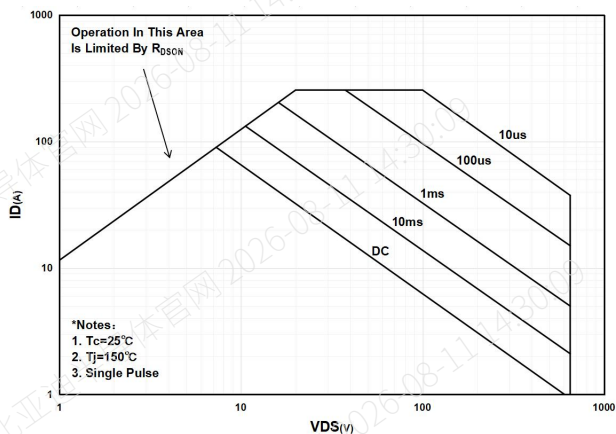


Figure 13. Safe operating area

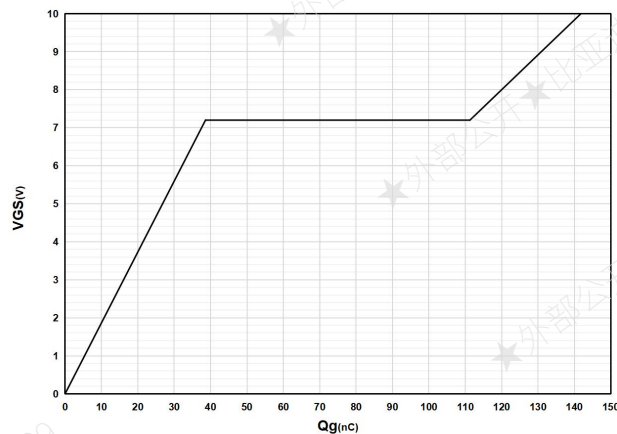


Figure 14. Typical gate Charge ($V_{DS}=400\text{V}$, $I_D=24\text{A}$)

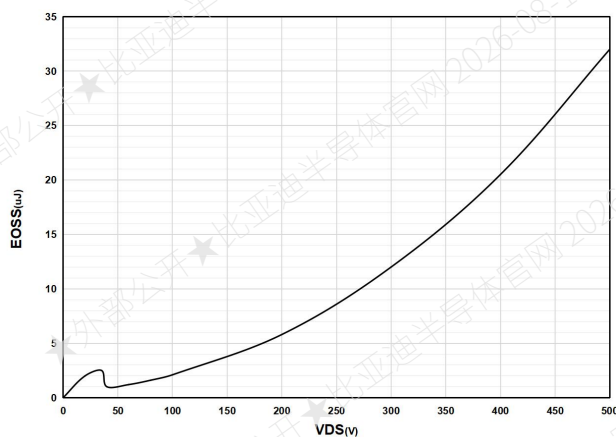


Figure 15. Typical Coss stored energy

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TEST CIRCUITS & WAVEFORMS

测试电路与波形

Diode characteristics

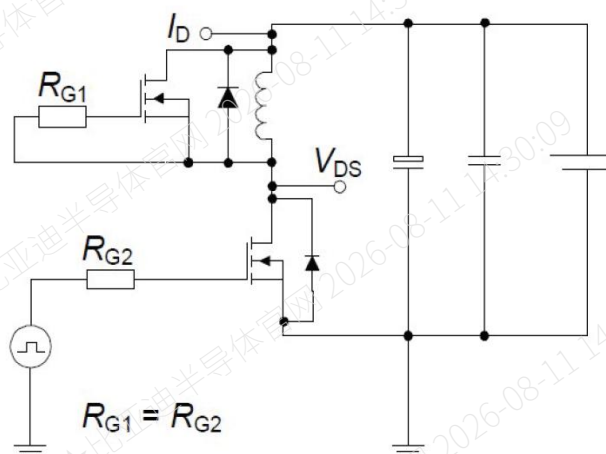


Figure 1. Test circuit for diode characteristics

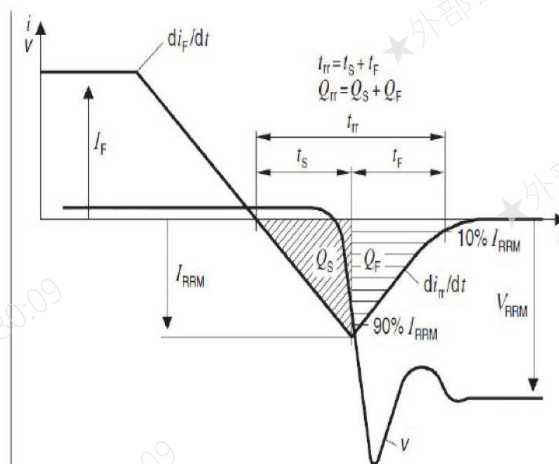


Figure 2. Diode recovery waveform

Switching time

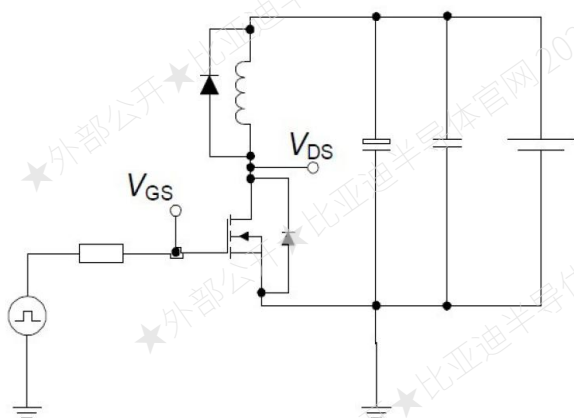


Figure 3. Switching time test circuit for inductive load

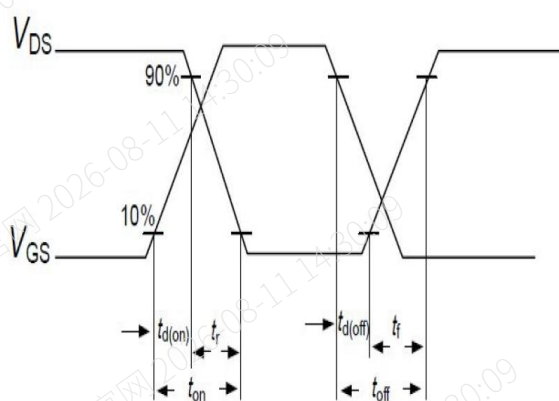


Figure 4. Switching time waveform

Unclamped inductive load

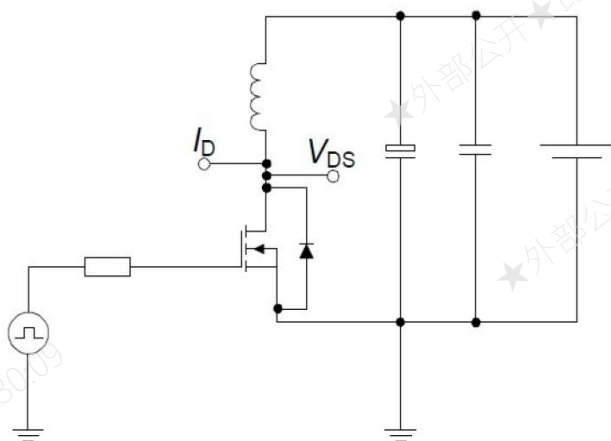


Figure 5. Unclamped inductive load test circuit

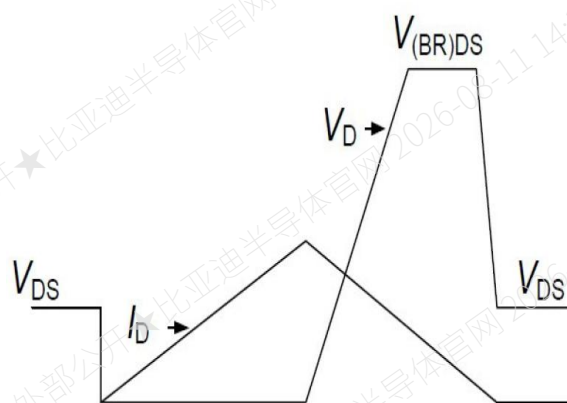


Figure 6. Unclamped inductive waveform



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TO247-4L Packing Outline Dimensions: TO247-4L 封装外形尺寸

Dim.	Mechanical Dimensions /mm	
	MIN	MAX
A	4.83	5.21
A1	1.90	2.16
B	1.07	1.33
B2	2.39	2.94
C	0.55	0.68
D	23.25	23.65
D1	16.35	16.75
E	15.74	16.14
F1	3.68	5.10
e	2.34	2.74
e1	4.88	5.28
L	17.31	17.82
L1	3.97	4.37
ΦP2	3.50	3.70
S	6.05	6.27
Q	5.49	6.00

Note: The mold may vary little from different packaging plants, please refer to the actual product.
备注：因封装厂的模具存在细微差异，请以实物的尺寸为准

Packing 包装

Packing	pcs/ inner box	inner box/ carton	pcs/carton
Tube	360	6	2160



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DISCLAIMER 免责声明

- Warranty Period: Unless otherwise agreed in the COOPERATION AGREEMENT or other WRITTEN DOCUMENTS, the Warranty Period for products specified in this specification shall be one year from the date of purchase if the products are properly preserved.

Special instructions: Storage Temperature: $20\pm 5^{\circ}\text{C}$; Relative Humidity: 30%-60%; The product should be stored in a place away from direct light and vibration.

质保期: 除双方在合作协议或其他书面文件中另行约定外, 产品妥当保存的情况下自购买之日起, 本规格书所述产品质保期为一年。

特殊说明: 储存温度: $20\pm 5^{\circ}\text{C}$; 相对湿度: 30%-60%; 产品应放置于避光地方, 避免震动。

- Our Company is committed to enhancing product quality and stability. This specification serves solely to delineate technical product details.

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safety standards, including but not limited to redundant design, fire prevention measures, and fault prevention, to design and maintain a safe and stable system environment. Customers must verify all functionalities described in this specification before or during actual application to ensure product suitability, safety (preventing potential accidents, fires, or public harm etc.), and reliability. It is recommended that Customers consult our company prior to testing to confirm whether the product information adequately covers the application requirements.

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- This specification is written in both Chinese and English, and in case of any conflict between the Chinese and English versions, the Chinese version shall prevail.

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